NSN 5962-01-163-9213

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View Online at https://aerobasegroup.com/nsn/5962-01-163-9213

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches a	nd 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dissip	Dation Rating:
739.0 milliwatts	
Operating Tempurature	e Range:
-55.0/+125.0 degrees ce	Isius
Storage Tempurature F	lange:
-65.0/+150.0 degrees ce	Isius
End Application:	
Radar system an/fps-117	7
Features Provided:	
Hermetically sealed and	burn in and bipolar and schottky and programmable and w/enable and w/active pull-up
Inclosure Material:	
Ceramic	
Inclosure Configuration	n:
Dual-in-line	
Output Logic Form:	
Transistor-transistor logi	c
Input Circuit Pattern:	
10 input	
Case Outline Source A	nd Designator:
D-2 mil-m-38510	
Terminal Surface Treat	ment:
Solder	
Voltage Rating And Ty	pe Per Characteristic:
5.5 volts power source	
Time Rating Per Chacte	eristic:
75.00 nanoseconds pro	pagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Qua	antity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

